

GL8□□48 Series "q,"are Type 'ED 'amps

■ Model No.

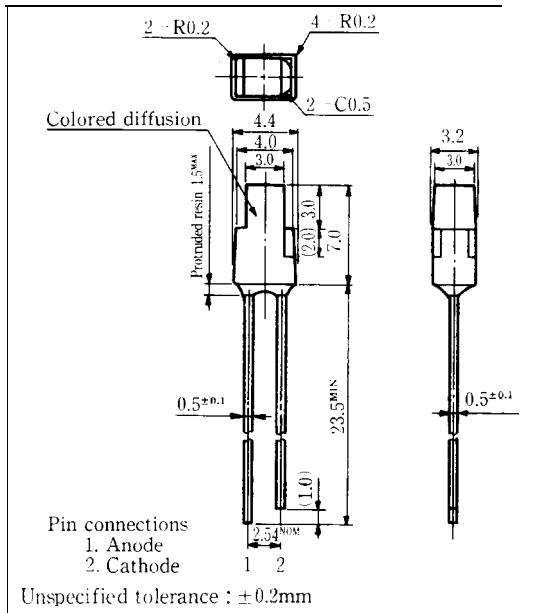
GL8HD48	Red	GaAsP/GaP
GL8HY48	Yellow	GaAsP/GaP
GL8EG48	Yellow-green	GaP

■ Features

1. 3.0mm×3.0mm square type
all resin mold
2. Colored diffusion lens type

■ Outline Dimensions

(Unit: mm)



■ Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	GL8HD48	GL8EG48					
		GL8HY48						
Power dissipation	P	84	84					mW
Continuous forward current	I _F	30	30					mA
*1Peak forward current	I _{FM}	50	50					mA
Derating factor	DC	—	0.40	0.40				m A/°C
	Pulse		0.67	0.67				m A/°C
Reverse voltage	V _R	5	5					v
Operating temperature	T _{opr}			-25	to	+85		°C
Storage temperature	T _{stg}			-25	to	+100		°C
*2Soldering temperature	T _{sol}			260	(within 5 seconds)			°C

*1 Duty ratio = 1/10, Pulse width = 0.1ms

*2 At the position of 1.6mm from the bottom face of resin package

SHARP

"In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that occur in equipment using any of SHARP's devices, shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest version of the device specification sheets before using any SHARP's device." **171**

GL8HD48 (Red)

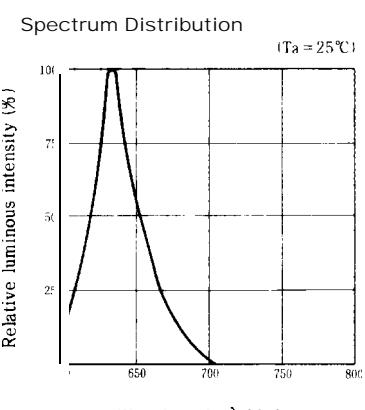
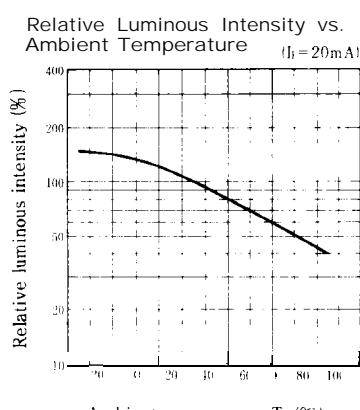
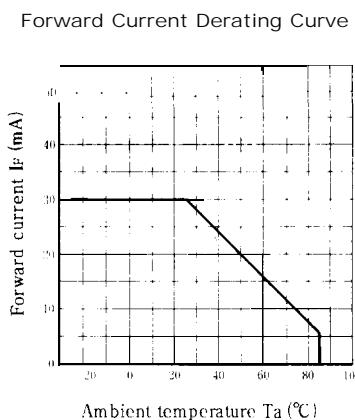
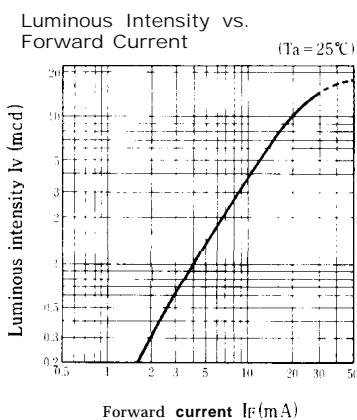
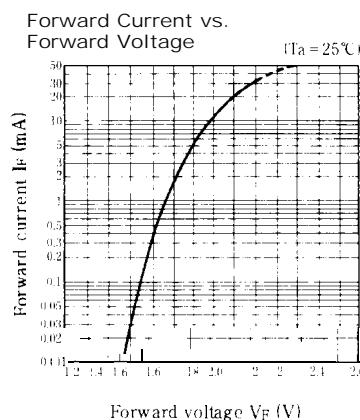
■ Electro-optical Characteristics

(Ta=25°C)

Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	GL8HD48	I _F =20mA		2.0	2.8	V
*3 Luminous intensity	I _V	GL8HD48	I _F =20mA	2.0	10	—	mcd
Peak emission wavelength	λ _p	GL8HD48	I _F =20mA	—	635	—	nm
Spectrum radiation bandwidth	Δλ	GL8HD48	I _F =20mA	—	35	—	nm
Reverse current	I _R	GL8HD48	V _R =4V	—	—	10	μA
Terminal capacitance	C _t	GL8HD48	V=OV f=1 MHz	—	20	—	pF
Response frequency	f _c	GL8HD48	—	—	4	—	MHz

*3 Tolerance: ±30%

■ Characteristics Diagrams



GL8HY48 (Yellow)

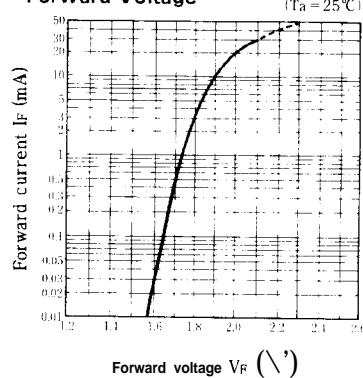
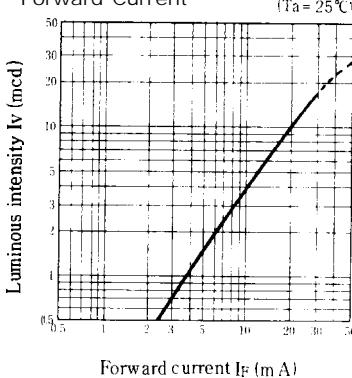
■ Electro-optical Characteristics

(Ta=25°C)

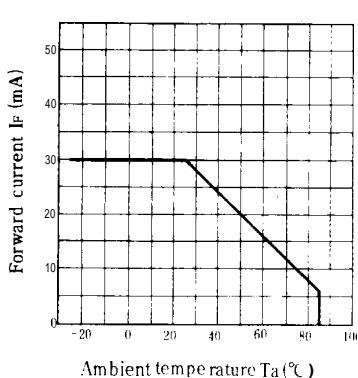
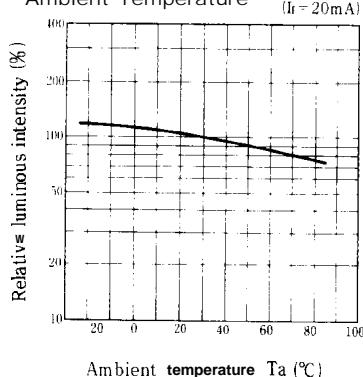
Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	GL8HY48	I _F =20mA		2.0	2.8	V
※3 Luminous intensity	I _V	GL8HY48	I _F =20mA	2.5	10	-	mcd
Peak emission wavelength	λ_p	GL8HY48	I _F =20mA	-	585	-	nm
Spectrum radiation bandwidth	$\Delta\lambda$	GL8HY48	I _F =20mA	-	30	-	nm
Reverse current	I _R	GL8HY48	V _R =4V	-	-	10	μA
Terminal capacitance	C _t	GL8HY48	V=0V f=1 MHz	-	35	-	pF
Response frequency	f _c	GL8HY48	-	-	4	-	MHz

※3 Tolerance: ±30%

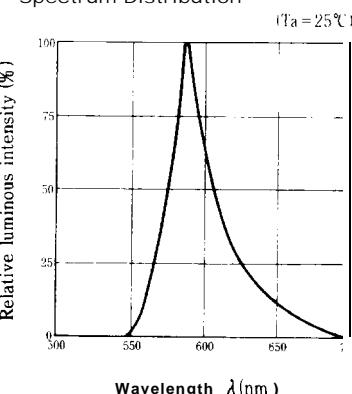
■ Characteristics Diagrams

Forward Current vs.
Forward VoltageLuminous Intensity I_V (mcd)

Forward Current Derating Curve

Relative Luminous Intensity vs.
Ambient Temperature

Spectrum Distribution



GL8EG48 (Yellow-green)

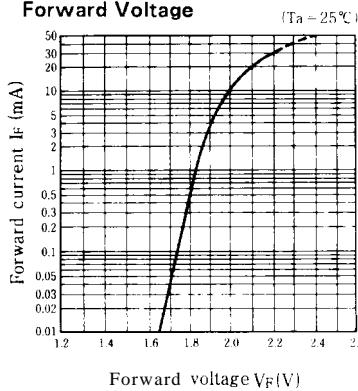
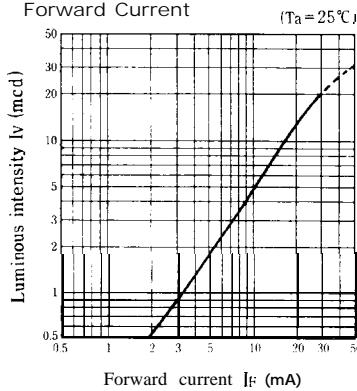
■ Electro-optical Characteristics

(Ta = 25°C)

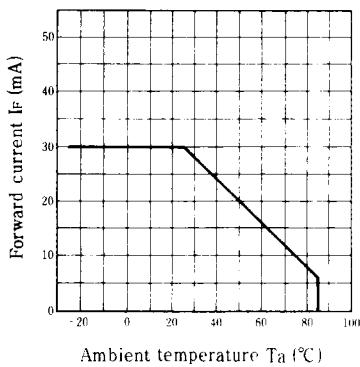
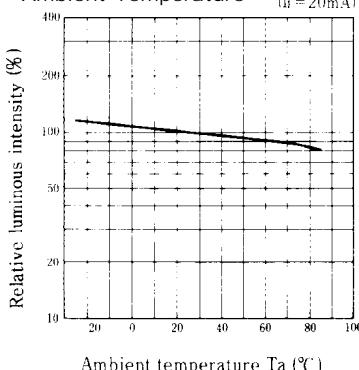
Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	GL8EG48	I _F = 20mA		2.1	2.8	V
※3 Luminous intensity	I _V	GL8EG48	I _F = 20mA	2.5	12	—	mcd
Peak emission wavelength	λ_p	GL8EG48	I _F = 20mA		565	—	nm
Spectrum radiation bandwidth	$\Delta\lambda$	GL8EG48	I _F = 20mA		30	—	nm
Reverse current	I _R	GL8EG48	V _R = 4V	—	—	10	μA
Terminal capacitance	C _t	GL8EG48	V = 0V f = 1 MHz	—	35	—	pF
Response frequency	f _c	GL8EG48	—	—	4	—	MHz

※3 Tolerance: ±30%

■ Characteristics Diagrams

Forward Current vs.
Forward VoltageLuminous Intensity vs.
Forward Current

Forward Current Derating Curve

Relative Luminous Intensity vs.
Ambient Temperature

Spectrum Distribution

